



### 30V P-Channel Enhancement Mode MOSFET

Voltage

-30 V

Current

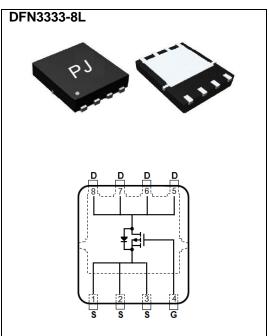
-50 A

#### **Features**

- $R_{DS(ON)}$ ,  $V_{GS}@-10V$ ,  $I_D@-10A<8.5m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}@-4.5V$ , $I_D@-8A<14m\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

- Case: DFN3333-8L Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.001 ounces, 0.03 grams



### **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		$V_{DS}$	-30	V
Gate-Source Voltage		$V_{GS}$	<u>+</u> 20	V
Continuous Drain Current	T <sub>C</sub> =25°C	I <sub>D</sub>	-50	
	T <sub>C</sub> =100°C		-32	Α
Pulsed Drain Current (Note 1)	T <sub>C</sub> =25°C	I <sub>DM</sub>	-200	
Power Dissipation	T <sub>C</sub> =25°C	P <sub>D</sub>	60	10/
	T <sub>C</sub> =100°C		24	W
Continuous Drain Current	T <sub>A</sub> =25°C	I <sub>D</sub>	-10	Α
	T <sub>A</sub> =70°C		-8	Α
Power Dissipation	T <sub>A</sub> =25°C	-	2.0	10/
Power Dissipation	T <sub>A</sub> =70°C	Pb	1.3	W
Operating Junction and Storage Temperature Range		$T_J, T_{STG}$	-55~150	°C
Typical Thermal Resistance (Note 4,5)	Junction to Case	$R_{ heta JC}$	2.1	9000
	Junction to Ambient	$R_{\theta JA}$	62.5	°C/W

Limited only By Maximum Junction Temperature





# **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS		
Static								
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V,I <sub>D</sub> =-250uA	-30	-	-	V		
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=-250$ uA	-1.0	-1.5	-2.5	V		
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-10V,I <sub>D</sub> =-10A	-	7.1	8.5	mΩ		
Diam-Source On-State Resistance		V <sub>GS</sub> =-4.5V,I <sub>D</sub> =-8A	-	10	14			
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS}$ =-30V, $V_{GS}$ =0V	-	-	-1.0	uA		
Gate-Source Leakage Current	$I_{GSS}$	V <sub>GS</sub> = <u>+</u> 20V,V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA		
Dynamic (Note 6)								
Total Gate Charge	$Q_g$	V <sub>DS</sub> =-15V, I <sub>D</sub> =-10A,	-	27	-	nC		
Gate-Source Charge	$Q_gs$		-	8.4	-			
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> 4.5 V	-	8.7	-			
Input Capacitance	Ciss	V <sub>DS</sub> =-15V, V <sub>GS</sub> =0V,	-	3228	-	pF		
Output Capacitance	Coss	f=1.0MHZ	-	396	-			
Reverse Transfer Capacitance	Crss	1-1.0WI IZ	-	254	-			
Turn-On Delay Time	td <sub>(on)</sub>	\/ 45\/\ID 4A	-	10	-	ns		
Turn-On Rise Time	t <sub>r</sub>	$V_{DS}$ =-15V,ID=-1A, $V_{GS}$ =-10V, R <sub>G</sub> =6 $\Omega$	-	13	-			
Turn-Off Delay Time	td <sub>(off)</sub>	(Note 1,2)	-	111	-			
Turn-Off Fall Time	t <sub>f</sub>		-	51	-			
Drain-Source Diode								
Maximum Continuous Drain-Source	ı				-50	Α		
Diode Forward Current	I <sub>S</sub>		_	-	-50	^		
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =-1A,V <sub>GS</sub> =0V	-	-0.7	-1	V		

#### NOTES:

- 1. Pulse width<a></a>300us, Duty cycle<a></a>2%
- 2. Essentially independent of operating temperature typical characteristics
- 3. Repetitive rating, pulse width limited by junction temperature  $T_{J(MAX)}$ =150°C. Ratings are based on low frequency and duty cycles to keep initial  $T_J$  =25°C.
- 4. The maximum current rating is package limited
- 5. R<sub>OJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper
- 6. Guaranteed by design, not subject to production testing.





#### **TYPICAL CHARACTERISTIC CURVES**

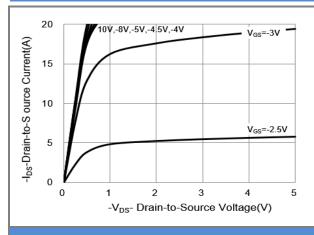
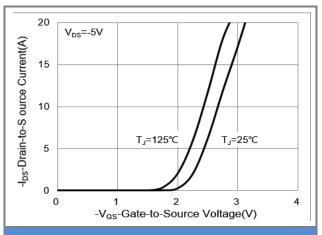


Fig.1 On-Region Characteristics



**Fig.2 Transfer Characteristics** 

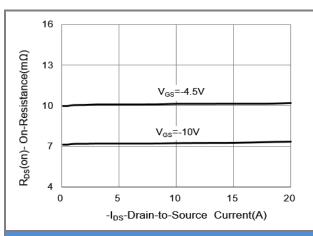


Fig.3 On-Resistance vs. Drain Current

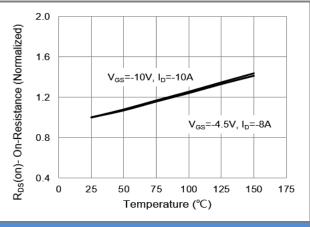


Fig.4 On-Resistance vs. Junction temperature

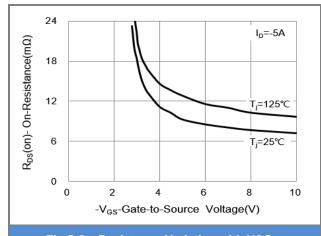


Fig.5 On-Resistance Variation with VGS.

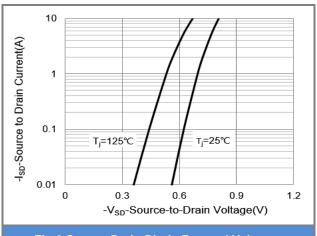


Fig.6 Source-Drain Diode Forward Voltage





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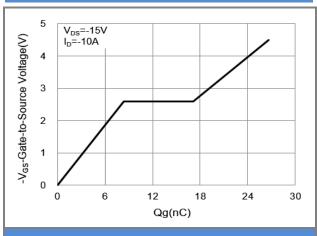


Fig.7 Gate-Charge Characteristics

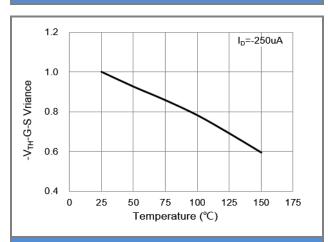


Fig.9 Threshold Voltage Variation with Temperature

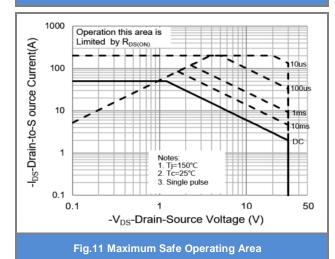


Fig.8 Breakdown Voltage Variation vs. Temperature.

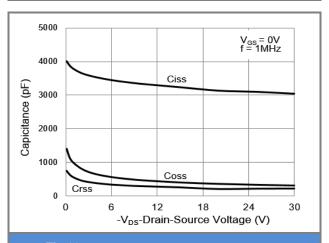


Fig.10 Capacitance vs. Drain-Source Voltage





### **TYPICAL CHARACTERISTIC CURVES**

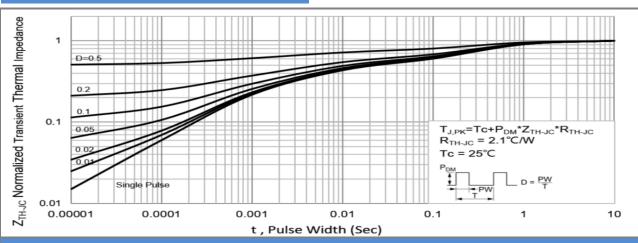


Fig.12 Normalized Transient Thermal Impedance vs. Pulse Width

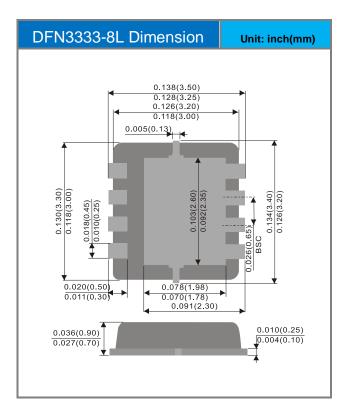


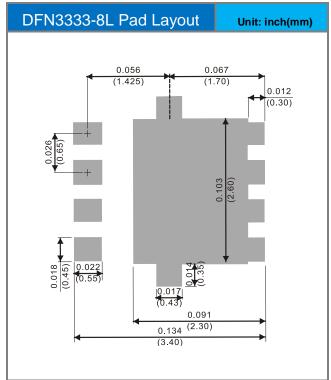


### **Part No Packing Code Version**

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJQ4401P_R2_00001	DFN3333-8L	5K pcs / 13" reel	4401	Halogen free

### **Packaging Information & Mounting Pad Layout**









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